

# COMLINEAR® CLC1050, CLC2050, CLC4050

# Low Power, 3V to 36V, Single, Dual, Quad Amplifiers

#### **FEATURES**

- Unity gain stable
- 100dB voltage gain
- 550kHz unity gain bandwidth
- 0.5mA supply current
- 20nA input bias current
- 2mV input offset voltage
- 3V to 36V single supply voltage range
- ±1.5V to ±18V dual supply voltage range
- Input common mode voltage range includes ground
- 0V to V<sub>S</sub>-1.5V output voltage swing
- CLC2050: improved replacement for industry standard LM358
- CLC4050: Improved replacement for industry standard LM324
- CLC1050: Pb-free SOT23-5
- CLC2050: Pb-free SOIC-8
- CLC4050: Pb-free SOIC-14

#### **APPLICATIONS**

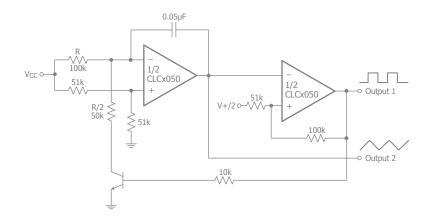
- Battery Charger
- Active Filters
- Transducer amplifiers
- General purpose controllers
- General purpose instruments

#### **General Description**

The COMLINEAR CLC1050 (single), CLC2050 (dual), and CLC4050 (quad) are voltage feedback amplifiers that are internally frequency compensated to provide unity gain stability. At unity gain (G=1), these amplifiers offer 550kHz of bandwidth. They consume only 0.5mA of supply current over the entire power supply operating range. The CLC1050, CLC2050, and CLC4050 are specifically designed to operate from single or dual supply voltages.

The COMLINEAR CLC1050, CLC2050, and CLC4050 offer a common mode voltage range that includes ground and a wide output voltage swing. The combination of low-power, high supply voltage range, and low supply current make these amplifiers well suited for many general purpose applications and as alternatives to several industry standard amplifiers on the market today.

### Typical Application - Voltage Controlled Oscillator (VCO)

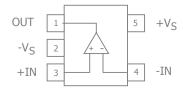


### **Ordering Information**

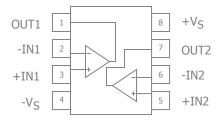
Part Number	Package	Pb-Free	RoHS Compliant	Operating Temperature Range	Packaging Method
CLC1050IST5X	SOT23-5	Yes	Yes	-40°C to +85°C	Reel
CLC2050ISO8X	SOIC-8	Yes	Yes	-40°C to +85°C	Reel
CLC4050ISO14X	SOIC-14	Yes	Yes	-40°C to +85°C	Reel

Moisture sensitivity level for all parts is MSL-1.

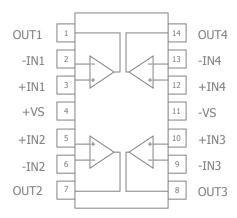
# **CLC1050 Pin Configuration**



# **CLC2050 Pin Configuration**



## **CLC4050 Pin Configuration**



### **CLC1050** Pin Assignments

Pin No.	Pin Name	Description
1	OUT	Output
2	-V <sub>S</sub>	Negative supply
3	+IN	Positive input
4	-IN	Negative input
5	+V <sub>S</sub>	Positive supply

## **CLC2050 Pin Configuration**

Pin No.	Pin Name	Description
1	OUT1	Output, channel 1
2	-IN1	Negative input, channel 1
3	+IN1	Positive input, channel 1
4	-V <sub>S</sub>	Negative supply
5	+IN2	Positive input, channel 2
6	-IN2	Negative input, channel 2
7	OUT2	Output, channel 2
8	+V <sub>S</sub>	Positive supply

# **CLC4050 Pin Configuration**

Pin No.	Pin Name	Description
1	OUT1	Output, channel 1
2	-IN1	Negative input, channel 1
3	+IN1	Positive input, channel 1
4	+Vs	Positive supply
5	+IN2	Positive input, channel 2
6	-IN2	Negative input, channel 2
7	OUT2	Output, channel 2
8	OUT3	Output, channel 3
9	-IN3	Negative input, channel 3
10	+IN3	Positive input, channel 3
11	-V <sub>S</sub>	Negative supply
12	+IN4	Positive input, channel 4
13	-IN4	Negative input, channel 4
14	OUT4	Output, channel 4

### **Absolute Maximum Ratings**

The safety of the device is not guaranteed when it is operated above the "Absolute Maximum Ratings". The device should not be operated at these "absolute" limits. Adhere to the "Recommended Operating Conditions" for proper device function. The information contained in the Electrical Characteristics tables and Typical Performance plots reflect the operating conditions noted on the tables and plots.

Parameter	Min	Max	Unit
Supply Voltage	0	40	V
Differential Input Voltage		40	V
Input Voltage	-0.3	40	V
Power Dissipation ( $T_A = 25$ °C) - SOIC-8		550	mW
Power Dissipation (T <sub>A</sub> = 25°C) - SOIC-14		800	mW

### **Reliability Information**

Parameter	Min	Тур	Max	Unit
Junction Temperature			150	°C
Storage Temperature Range	-65		150	°C
Lead Temperature (Soldering, 10s)			260	°C
Package Thermal Resistance				
SOT23-5		221		°C/W
SOIC-8		100		°C/W
SOIC-14		88		°C/W

Notes:

Package thermal resistance ( $\theta_{JA}$ ), JDEC standard, multi-layer test boards, still air.

### **Recommended Operating Conditions**

Parameter	Min	Тур	Max	Unit
Operating Temperature Range	-40		+85	°C
Supply Voltage Range	3 (±1.5)		36 (±18)	V

### **Electrical Characteristics**

 $T_A$  = 25°C (if **bold**,  $T_A$  = -40 to +85°C),  $V_S$  = +5V, - $V_S$  = GND,  $R_f$  =  $R_g$  =2k $\Omega$ ,  $R_L$  = 2k $\Omega$  to  $V_S/2$ , G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Frequency D	omain Response	<u>'</u>				
LICDW/	Linity Coin Bondwidth	$G = +1$ , $V_{OUT} = 0.2V_{pp}$ , $V_{S} = 5V$		330		kHz
UGBW <sub>SS</sub>	Unity Gain Bandwidth	$G = +1$ , $V_{OUT} = 0.2V_{pp}$ , $V_{S} = 30V$		550		kHz
D///	-3dB Bandwidth	$G = +2$ , $V_{OUT} = 0.2V_{pp}$ , $V_{S} = 5V$		300		kHz
BW <sub>SS</sub>	-Sub Balluwiduli	$G = +1$ , $V_{OUT} = 0.2V_{pp}$ , $V_S = 30V$		422		kHz
$BW_{LS}$	Large Signal Bandwidth	$G = +2$ , $V_{OUT} = 1V_{pp}$ , $V_{S} = 5V$		107		kHz
		$G = +2$ , $V_{OUT} = 2V_{pp}$ , $V_{S} = 30V$		76		kHz
Time Domair	Response			T		1
t <sub>R</sub> , t <sub>F</sub>	Rise and Fall Time	$V_{OUT} = 1V$ step; (10% to 90%), $V_S = 5V$		4		μs
		$V_{OUT} = 2V$ step; (10% to 90%), $V_S = 30V$		5.6		μs
OS	Overshoot	V <sub>OUT</sub> = 0.2V step		1		%
SR	Slew Rate	$1V$ step, $V_S = 5V$		200		V/ms
		$4V$ step, $V_S = 30V$		285		V/ms
Distortion/No	pise Response					
THD	Total Harmonic Distortion	$V_{OUT} = 2V_{pp}$ , $f = 1kHz$ , $G = 20dB$ , $C_L = 100pF$ , $V_S = 30V$		0.015		%
		> 10kHz, V <sub>S</sub> = 5V		45		nV/√Hz
e <sub>n</sub>	Input Voltage Noise	> 10kHz, V <sub>S</sub> = 30V		40		nV/√Hz
X <sub>TALK</sub>	Crosstalk	Channel-to-channel, 1kHz to 20kHz		120		dB
DC Performa	nce	,				
		V 4.0/ 5 00 V 5// 20V		2	5	mV
$V_{IO}$	Input Offset Voltage (1)	$V_{OUT} = 1.4V$ , $R_S = 0\Omega$ , $V_S = 5V$ to 30V			7	mV
dV <sub>IO</sub>	Average Drift			7		μV/°C
т.	Inch Bine Comment (1)	$V_{CM} = 0V$		20	100	nA
$I_b$	Input Bias Current (1)				200	nA
т.	Transit Officet Commont (1)			5	30	nA
$I_{OS}$	Input Offset Current (1)	$V_{CM} = 0V$			100	nA
DCDD	Dower Cumply Dejection Datio (1)	DC V 5VV 20V	70	100		dB
PSRR	Power Supply Rejection Ratio (1)	DC, $V_S = 5V$ to 30V	60			dB
۸	Open Lean Cain (1)	0 : (1)	85	100		dB
A <sub>OL</sub>	Open-Loop Gain (1)	$+V_S = 15V$ , $R_L = \ge 2kΩ$ , $V_{OUT} = 1V$ to 11V	80			dB
	Cumbic Current Cl C10F0 (1)	$R_L = \infty$ , $V_S = 30V$		0.65	1.5	mA
	Supply Current, CLC1050 (1)	$R_L = \infty$ , $V_S = 5V$		0.45	1.0	mA
т	Supply Current, CLC2050 (1)	$R_L = \infty$ , $V_S = 30V$		0.7	2.0	mA
$I_{S}$	Supply Current, CEC2050 (4)	$R_L = \infty$ , $V_S = 5V$		0.5	1.2	mA
	Supply Current, CLC4050 (1)	$R_L = \infty$ , $V_S = 30V$		1.0	3.0	mA
	Supply Current, CLC+030 (4)	$R_L = \infty$ , $V_S = 5V$		0.7	1.2	mA
Input Charac	teristics					
CMIR	Common Mode Input Range (1,3)	+V <sub>S</sub> = 30V	0		+V <sub>S</sub> - 1.5	V
CMRR	Common Mode Rejection Ratio (1)	DC, V <sub>CM</sub> = 0V to (+V <sub>S</sub> - 1.5V)	60	70		dB
Output Chara		56, *CM - 5* &(. *S 1.5*)	60			dB
Output Clidia	ucter istics		36			V
		$+V_S = 30V$ , $R_L = 2k\Omega$	26			V
$V_{OH}$	Output Voltage Swing, High (1)		26	20		V
		$+V_{S} = 30V, R_{L} = 10k\Omega$	27	28		V
		3 337712 23.00	27			V

#### **Electrical Characteristics continued**

 $T_A = 25$ °C (if **bold**,  $T_A = -40$  to +85°C),  $V_S = +5V$ ,  $-V_S = GND$ ,  $R_f = R_g = 2k\Omega$ ,  $R_L = 2k\Omega$  to  $V_S/2$ , G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
W	Outrout Voltage Suring Levy (1)	LV - FV D - 10k0		5	20	mV
V <sub>OL</sub>	Output Voltage Swing, Low (1)	$+V_S = 5V$ , $R_L = 10k\Omega$			30	mV
_	0.41.6(1)	V 4VV 0V V 45VV 2V	20	40		mA
ISOURCE	Output Current, Sourcing (1)	$V_{IN+} = 1V$ , $V_{IN-} = 0V$ , $+V_S = 15V$ , $V_{OUT} = 2V$				
		V 0VV 1V 1V 1FVV 2V	10	15		mA
I <sub>SINK</sub>	Output Current, Sinking (1)	$V_{IN+} = 0V$ , $V_{IN-} = 1V$ , $+V_S = 15V$ , $V_{OUT} = 2V$	5			
		$V_{IN+} = 0V$ , $V_{IN-} = 1V$ , $+V_S = 15V$ , $V_{OUT} = 0.2V$	12	50		μΑ
$I_{SC}$	Short Circuit Output Current (1)	$+V_S = 15V$		40	60	mA

#### Notes:

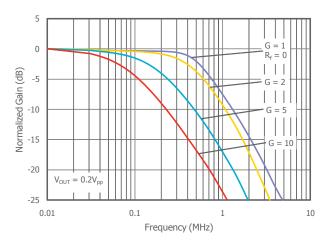
- 1. 100% tested at 25°C. (Limits over the full temperature range are guaranteed by design.)
- 2. The input common mode voltage of either input signal voltage should be kept > 0.3V at 25°C. The upper end of the common-mode voltage range is  $+V_S 1.5$ V at 25°C, but either or both inputs can go to +36V without damages, independent of the magnitude of  $V_S$ .

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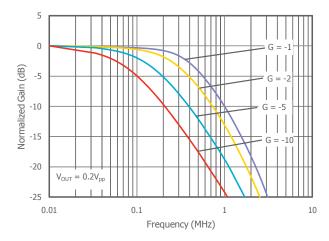
### **Typical Performance Characteristics**

 $T_A = 25$ °C,  $+V_S = 30$ V,  $-V_S = GND$ ,  $R_f = R_q = 2k\Omega$ ,  $R_L = 2k\Omega$ , G = 2; unless otherwise noted.

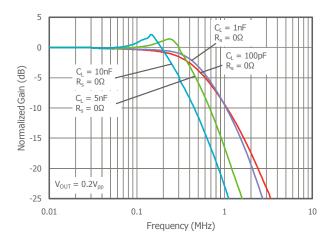
### Non-Inverting Frequency Response



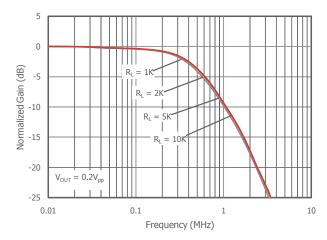
#### Inverting Frequency Response



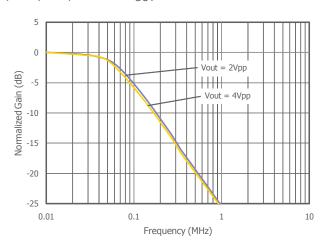
### Frequency Response vs. C<sub>L</sub>



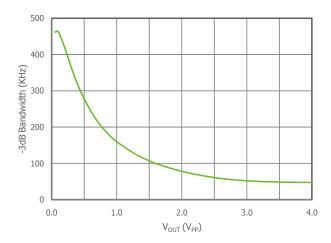
Frequency Response vs. R<sub>I</sub>



### Frequency Response vs. V<sub>OUT</sub>



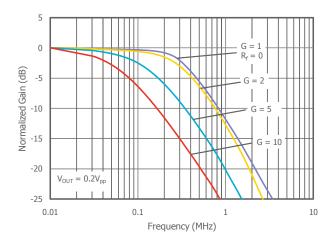
-3dB Bandwidth vs. V<sub>OUT</sub>



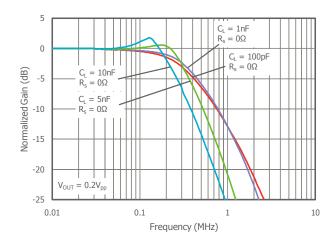
### **Typical Performance Characteristics**

 $T_A = 25$ °C,  $+V_S = 30$ V,  $-V_S = GND$ ,  $R_f = R_q = 2k\Omega$ ,  $R_L = 2k\Omega$ , G = 2; unless otherwise noted.

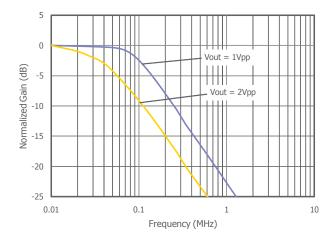
Non-Inverting Frequency Response at  $V_S = 5V$ 



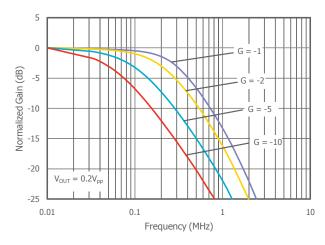
Frequency Response vs.  $C_L$  at  $V_S = 5V$ 



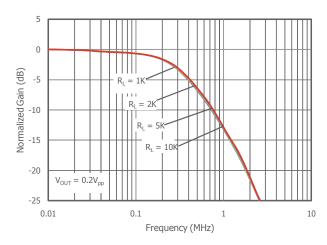
Frequency Response vs.  $V_{OUT}$  at  $V_S = 5V$ 



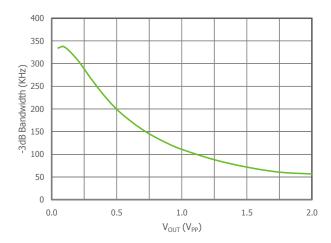
Inverting Frequency Response at  $V_S = 5V$ 



Frequency Response vs.  $R_L$  at  $V_S = 5V$ 



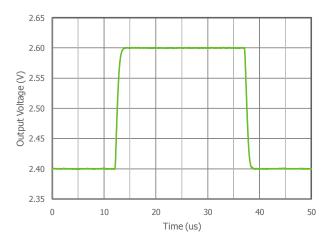
-3dB Bandwidth vs.  $V_{OUT}$  at  $V_S = 5V$ 



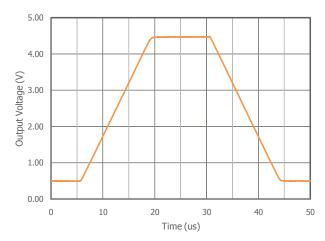
# Typical Performance Characteristics - Continued

 $T_A=25$  °C,  $+V_S=30$ V,  $-V_S=GND$ ,  $R_f=R_g=2k\Omega$ ,  $R_L=2k\Omega$ , G=2; unless otherwise noted.

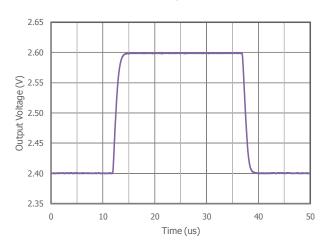
### Small Signal Pulse Response



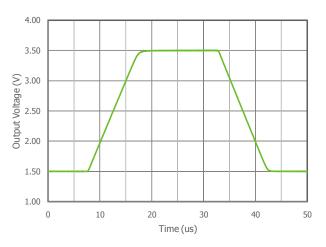
### Large Signal Pulse Response



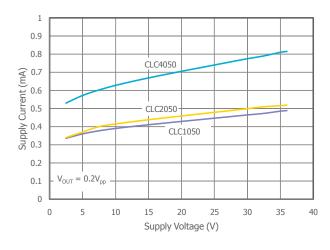
Small Signal Pulse Response at  $V_S = 5V$ 



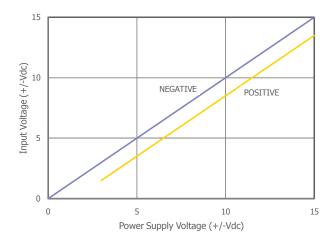
Large Signal Pulse Response at  $V_S = 5V$ 



#### Supply Current vs. Supply Voltage



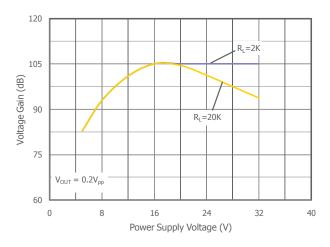
Input Voltage Range vs. Power Supply



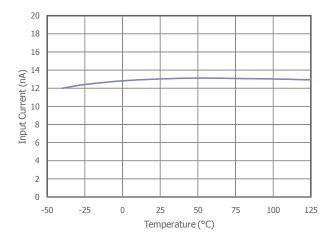
# Typical Performance Characteristics - Continued

 $T_A = 25$ °C,  $+V_S = 30$ V,  $-V_S = GND$ ,  $R_f = R_g = 2k\Omega$ ,  $R_L = 2k\Omega$ , G = 2; unless otherwise noted.

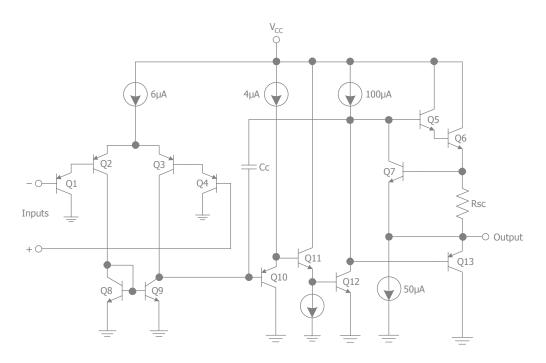
### Voltage Gain vs. Supply Voltage



### Input Current vs. Temperature



### Functional Block Diagram



#### **Application Information**

#### **Basic Operation**

Figures 1, 2, and 3 illustrate typical circuit configurations for non-inverting, inverting, and unity gain topologies for dual supply applications. They show the recommended bypass capacitor values and overall closed loop gain equations.

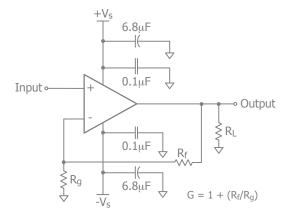


Figure 1. Typical Non-Inverting Gain Circuit

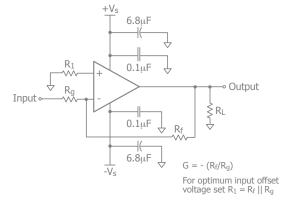


Figure 2. Typical Inverting Gain Circuit

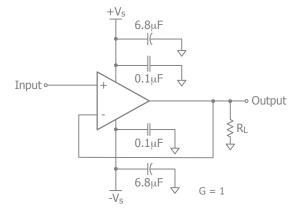


Figure 3. Unity Gain Circuit

#### **Power Dissipation**

Power dissipation should not be a factor when operating under the stated 2k ohm load condition. However, applications with low impedance, DC coupled loads should be analyzed to ensure that maximum allowed junction temperature is not exceeded. Guidelines listed below can be used to verify that the particular application will not cause the device to operate beyond it's intended operating range.

Maximum power levels are set by the absolute maximum junction rating of 150°C. To calculate the junction temperature, the package thermal resistance value Theta<sub>JA</sub>  $(\Theta_{1A})$  is used along with the total die power dissipation.

$$T_{Junction} = T_{Ambient} + (\Theta_{JA} \times P_{D})$$

Where T<sub>Ambient</sub> is the temperature of the working environment.

In order to determine  $P_D$ , the power dissipated in the load needs to be subtracted from the total power delivered by the supplies.

$$P_D = P_{supply} - P_{load}$$

Supply power is calculated by the standard power equation.

$$P_{\text{supply}} = V_{\text{supply}} \times I_{\text{RMS supply}}$$

$$V_{\text{supply}} = V_{S+} - V_{S-}$$

Power delivered to a purely resistive load is:

$$P_{load} = ((V_{LOAD})_{RMS^2})/Rload_{eff}$$

The effective load resistor (Rload<sub>eff</sub>) will need to include the effect of the feedback network. For instance,

Rload<sub>eff</sub> in figure 3 would be calculated as:

$$R_L \parallel (R_f + R_a)$$

These measurements are basic and are relatively easy to perform with standard lab equipment. For design purposes however, prior knowledge of actual signal levels and load impedance is needed to determine the dissipated power. Here,  $P_{\rm D}$  can be found from

$$P_D = P_{Quiescent} + P_{Dynamic} - P_{Load}$$

Quiescent power can be derived from the specified  $I_S$  values along with known supply voltage,  $V_{Supply}$ . Load power can be calculated as above with the desired signal amplitudes using:

 $(V_{LOAD})_{RMS} = V_{PEAK} / \sqrt{2}$ 

 $(I_{LOAD})_{RMS} = (V_{LOAD})_{RMS} / Rload_{eff}$ 

The dynamic power is focused primarily within the output stage driving the load. This value can be calculated as:

$$P_{DYNAMIC} = (V_{S+} - V_{LOAD})_{RMS} \times (I_{LOAD})_{RMS}$$

Assuming the load is referenced in the middle of the power rails or  $V_{\text{supply}}/2$ .

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the packages available.

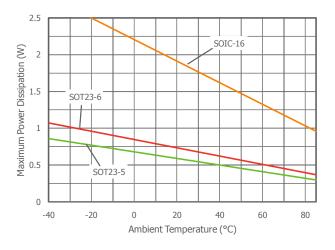


Figure 4. Maximum Power Derating

#### **Driving Capacitive Loads**

Increased phase delay at the output due to capacitive loading can cause ringing, peaking in the frequency response, and possible unstable behavior. Use a series resistance,  $R_S$ , between the amplifier and the load to help improve stability and settling performance. Refer to Figure 5.

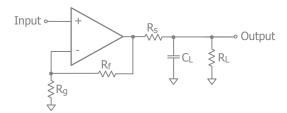


Figure 5. Addition of R<sub>S</sub> for Driving Capacitive Loads

Table 1 provides the recommended  $R_S$  for various capacitive loads. The recommended  $R_S$  values result in <=1dB peaking in the frequency response. The Frequency Response vs.  $C_L$  plot, on page 6, illustrates the response of the CLCx050.

C <sub>L</sub> (pF)	R <sub>S</sub> (Ω)	-3dB BW (kHz)
1nF	0	485
5nF	0	390
10nF	0	260
100	0	440

Table 1: Recommended R<sub>S</sub> vs. C<sub>L</sub>

For a given load capacitance, adjust  $R_S$  to optimize the tradeoff between settling time and bandwidth. In general, reducing  $R_S$  will increase bandwidth at the expense of additional overshoot and ringing.

#### Overdrive Recovery

An overdrive condition is defined as the point when either one of the inputs or the output exceed their specified voltage range. Overdrive recovery is the time needed for the amplifier to return to its normal or linear operating point. The recovery time varies, based on whether the input or output is overdriven and by how much the range is exceeded. The CLCx050 will typically recover in less than 30ns from an overdrive condition. Figure 6 shows the CLC1050 in an overdriven condition.

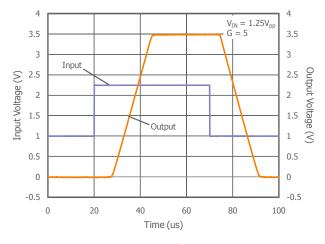


Figure 6. Overdrive Recovery

#### **Layout Considerations**

General layout and supply bypassing play major roles in high frequency performance. CADEKA has evaluation boards to use as a guide for high frequency layout and as an aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include  $6.8\mu F$  and  $0.1\mu F$  ceramic capacitors for power supply decoupling
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.1µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances
  Refer to the evaluation hoard layouts below for more in

Refer to the evaluation board layouts below for more information.

#### **Evaluation Board Information**

The following evaluation boards are available to aid in the testing and layout of these devices:

Evaluation Board	Products
CEB002	CLC1050
CEB006	CLC2050
CEB018	CLC4050

#### **Evaluation Board Schematics**

Evaluation board schematics and layouts are shown in Figures 7-14. These evaluation boards are built for dual- supply operation. Follow these steps to use the board in a single-supply application:

- 1. Short -Vs to ground.
- 2. Use C3 and C4, if the  $-V_S$  pin of the amplifier is not directly connected to the ground plane.

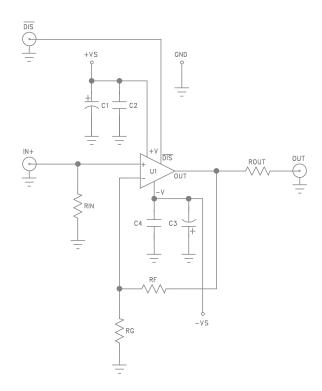


Figure 7. CEB002 Schematic

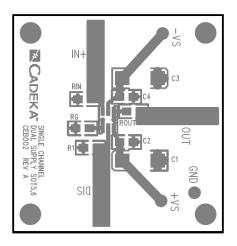


Figure 8. CEB002 Top View

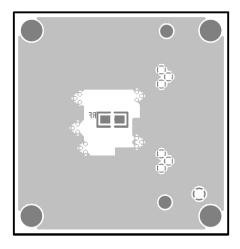


Figure 9. CEB002 Bottom View

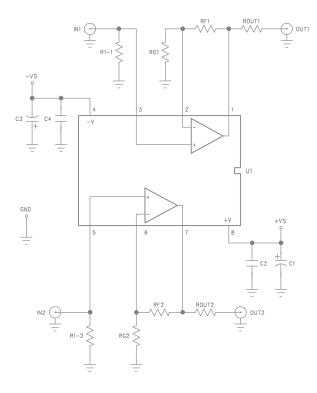


Figure 10. CEB006 Schematic

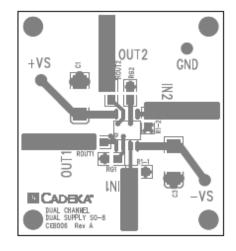


Figure 11. CEB006 Top View

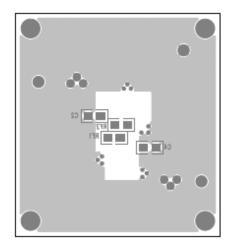


Figure 12. CEB006 Bottom View

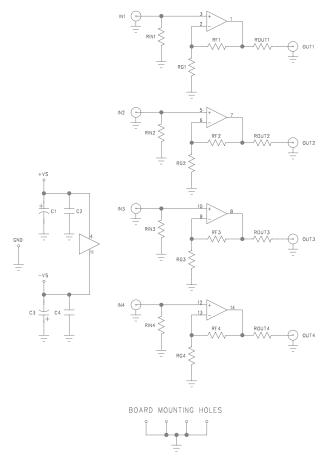


Figure 13. CEB018 Schematic

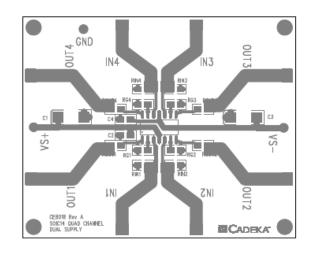


Figure 14 CEB018 Top View

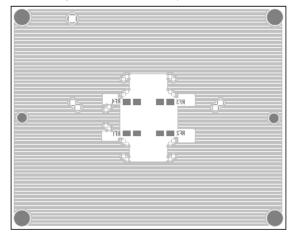


Figure 15. CEB018 Bottom View

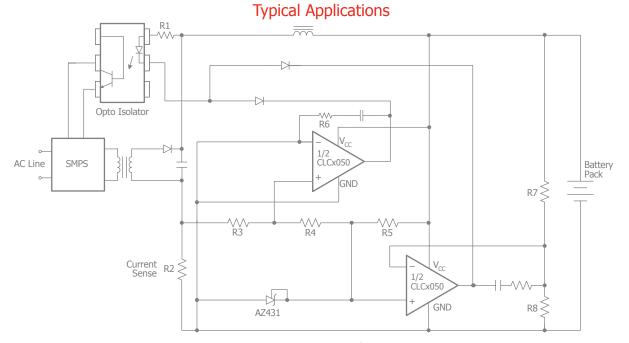


Figure 16. Battery Charger

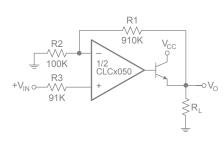


Figure 17. Power Amplifier

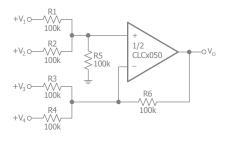


Figure 18. DC Summing Amplifier

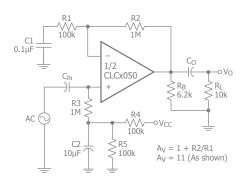


Figure 19. AC-Coupled Non-Inverting Amplifier

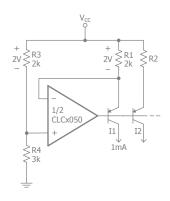


Figure 20. Fixed Current Sources

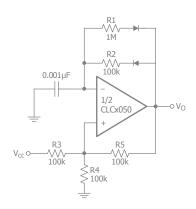


Figure 21. Pulse Generator

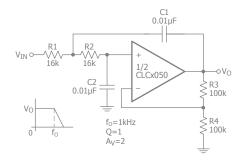
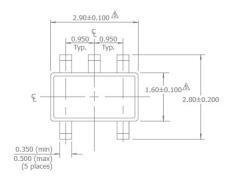
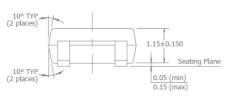


Figure 22. DC-Coupled Low-Pass Active Filter

### **Mechanical Dimensions**

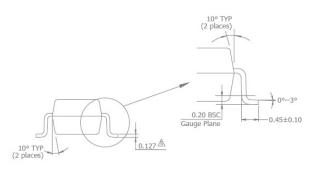
#### SOT23-5 Package



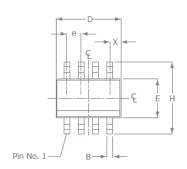


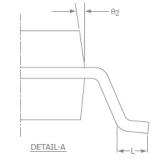
#### NOTES:

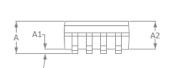
- 1. Dimensions and tolerances are as per ANSI Y14.5M-1982.
- 2. Package surface to be matte finish VDI 11 $\sim$ 13.
- 3. Die is facing up for mold. Die is facing down for trim/form, ie. reverse trim/form.
- 4. The footlength measuring is based on the guage plane method.
- $\Delta$  Dimension are exclusive of mold flash and gate burr.
- ≜ Dimension are exclusive of solder plating.

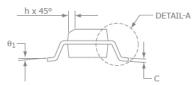


#### SOIC-8 Package









SOIC-8						
SYMBOL	MIN	MAX				
A1	0.10	0.25				
В	0.36	0.48				
С	0.19	0.25				
D	4.80	4.98				
Е	3.81	3.99				
е	1.27 BSC					
Н	5.80	6.20				
h	0.25	0.5				
L	0.41	1.27				
А	1.37	1.73				
θ1	0° 8°					
X	0.55 ref					
$\theta_2$	7º BSC					

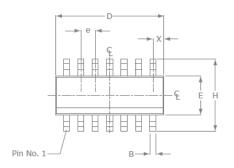
#### NOTE:

- 1. All dimensions are in millimeters.
- 2. Lead coplanarity should be 0 to 0.1mm (0.004") max.
- 3. Package surface finishing: VDI 24~27
- 4. All dimension excluding mold flashes.
- 5. The lead width, B to be determined at 0.1905mm from the lead tip.

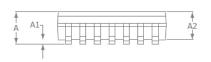
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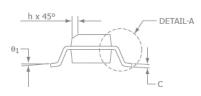
#### Mechanical Dimensions continued

#### SOIC-14 Package









SOIC-14		
SYMBOL	MIN	MAX
A1	0.10	0.25
В	0.36	0.48
С	0.19	0.25
D	8.56	8.74
Е	3.84	3.99
е	1.27 BSC	
Н	5.80	6.20
h	0.25	0.5
L	0.41	1.27
A	1.37	1.73
$\theta_1$	0°	80
X	0.51 ref	
θ <sub>2</sub>	7º BSC	

#### NOTE:

- 1. All dimensions are in millimeters.
- 2. Lead coplanarity should be 0 to 0.1mm (0.004") max  $\,$
- 3. Package surface finishing: VDI 24~27
- 4. All dimension excluding mold flashes.
- 5. The lead width, B to be determined at 0.1905mm from the lead tip.

#### For additional information regarding our products, please visit CADEKA at: cadeka.com

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